TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7MH240FK,TC7MH244FK

Octal Bus Buffer

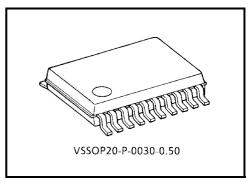
TC7MH240FK Inverted, 3-State Outputs TC7MH244FK Non-Inverted, 3-State Outputs

The TC7MH240FK and TC7MH244FK are advanced high speed CMOS octal bus buffers fabricated with silicon gate $\rm C^2MOS$ technology.

They achieve the high speed operation similar to equivalent bipolar schottky TTL while maintaining the CMOS low power dissipation.

The TC7MH240FK is an inverting 3-state buffer having two active-low output enables. The TC7MH244FK is a non-inverting 3-state buffer, and has two active-low output enables.

These devices are designed to be used with 3-state memory address drivers, etc.



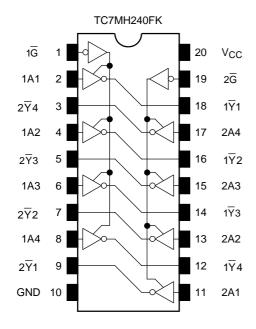
Weight: 0.03 g (typ.)

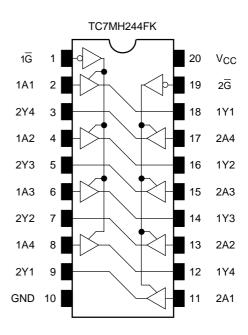
An input protection circuit ensures that 0 to 7 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

Features

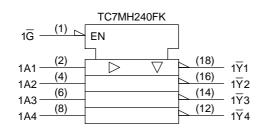
- High speed: $t_{pd} = 3.9 \text{ ns (typ.)} (V_{CC} = 5 \text{ V})$
- Low power dissipation: $ICC = 4 \mu A \text{ (max) (Ta = 25°C)}$
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_pLH \approx t_pHL$
- Wide operating voltage range: $V_{CC \text{ (opr)}} = 2 \sim 5.5 \text{ V}$
- Low noise: VOLP = 0.8 (max)
- Pin and function compatible with 74ALS240/244

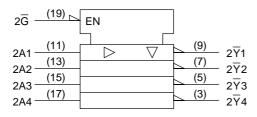
Pin Assignment (top view)

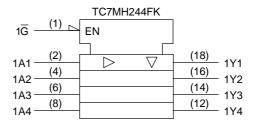


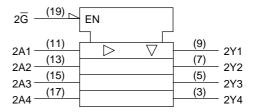


IEC Logic Symbol









Truth Table

Inp	uts	Outputs			
G	An	Yn	\overline{Y}_n		
L	L	L	Н		
L	Н	Н	L		
Н	Х	Z	Z		

X : Don't care

Z : High impedance

Y_n: TC7MH244FK

 \overline{Y}_n : TC7MH240FK

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Maximum Ratings

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7.0	V
DC input voltage	V _{IN}	-0.5~7.0	V
DC output voltage	Vout	-0.5~V _{CC} + 0.5	V
Input diode current	I _{IK}	-20	mA
Output diode current	I _{OK}	±20	mA
DC output current	I _{OUT}	±25	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	P _D	180	mW
Storage temperature	T _{stg}	-65~150	°C

Recommended Operating Conditions

Characteristics	Symbol	Rating	Unit	
Supply voltage	V _{CC}	2.0~5.5	V	
Input voltage	V _{IN}	0~5.5	V	
Output voltage	V _{OUT}	0~V _{CC}	V	
Operating temperature	T _{opr}	-40~85	°C	
Input rise and fall time	dt/dv	$0 \sim 100 \; (V_{CC} = 3.3 \pm 0.3 \; V)$	ns/V	
input noe and fail time	αι/αν	$0 \sim 20 \ (V_{CC} = 5 \pm 0.5 \ V)$	113/ V	

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Electrical Characteristics

DC Characteristics

Characteristics Symbol Test Condition		Cumbal	Symbol Tost Condition			Ta = 25°C			Ta = -4	Unit	
		V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic			
High level					2.0	1.50	_	_	1.50	_	
	High level	V_{IH}	_		3.0~5.5	V _{CC} × 0.7	_		V _{CC} × 0.7	_	V
Input voltage							_	0.50	_	0.50	V
	Low level	V_{IL}		_	3.0~5.5		_	V _{CC} × 0.3	_	V _{CC} × 0.3	
					2.0	1.9	2.0	_	1.9	_	
			V _{IN} = V _{IH} or V _{IL}	Ι _{ΟΗ} = -50 μΑ	3.0	2.9	3.0	_	2.9	_	
Output voltage	High level	V _{OH}			4.5	4.4	4.5	_	4.4	_	
				I _{OH} = -4 mA	3.0	2.58	_	_	2.48	_	
				$I_{OH} = -8 \text{ mA}$	4.5	3.94	_	_	3.80	_	
			V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0	0.1	_	0.1	
					3.0	_	0	0.1	_	0.1	
	Low level	Low level V _{OL}			4.5	_	0	0.1	_	0.1	
				$I_{OL} = 4 \text{ mA}$	3.0	_	_	0.36	_	0.44	
				$I_{OL} = 8 \text{ mA}$	4.5	_	_	0.36	_	0.44	
3-state output of	f-state current	I _{OZ}	$V_{IN} = V_{IH}$ or V_{IL} $V_{OUT} = V_{CC}$ or GND		5.5	_	_	±0.25	_	±2.50	μА
Input leakage cu	rrent	I _{IN}	V _{IN} = 5.5 V or GND		0~5.5			±0.1	_	±1.0	μА
Quiescent supply	y current	Icc	V _{IN} = V _{CC} or GND		5.5	_	_	4.0	_	40.0	μΑ



AC Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Symbol Test Condition		Test Condition		Ta = 25°C			Ta = -40~85°C	
Characteristics	Syllibol	rest Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	Unit
		_	3.3 ± 0.3	15	_	5.3	7.5	1.0	9.0	
Propagation delay time	t _{pLH}		3.3 ± 0.3	50	_	7.8	11.0	1.0	12.5	ns
(TC7MH240FK)	t _{pHL}		5.0 ± 0.5	15	_	3.6	5.5	1.0	6.5	113
			3.0 ± 0.3	50	_	5.1	7.5	1.0	8.5	
			3.3 ± 0.3	15	_	5.8	8.4	1.0	10.0	
Propagation delay time	t _{pLH}		3.3 ± 0.3	50		8.3	11.9	1.0	13.5	ns
(TC7MH244FK)	t _{pHL}	_	5.0 ± 0.5	15		3.9	5.5	1.0	6.5	ns
			3.0 ± 0.3	50		5.4	7.5	1.0	8.5	
	^t pZL ^t pZH	$R_L = 1 \text{ k}\Omega$	3.3 ± 0.3	15		6.6	10.6	1.0	12.5	- ns
3-state output enable time				50		9.1	14.1	1.0	16.0	
3-state output enable time			5.0 ± 0.5	15		4.7	7.3	1.0	8.5	
				50	_	6.2	9.3	1.0	10.5	
3-state output disable time	t _{pLZ}	$R_1 = 1 k\Omega$	3.3 ± 0.3	50		10.3	14.0	1.0	16.0	ns
5-state output disable time	t_{pHZ}		5.0 ± 0.5	50	_	6.7	9.2	1.0	10.5	115
Output to output skew	t _{osLH}	(Note1)	3.3 ± 0.3	50			1.5	_	1.5	ns
Output to output skew	t _{osHL}	(Note I)	5.0 ± 0.5	50			1.0	_	1.0	20
Input capacitance	C _{IN}	_		_	4	10	_	10	pF	
Output capacitance	C _{OUT}	_		_	6	_	_	_	pF	
Power dissipation		TC7MH240FK			_	17	_	_	_	n.E
capacitance (Note2)	C _{PD}	TC7MH244FK		_	19		_	_	pF	

Note1: Parameter guaranteed by design.

 $t_{OSLH} = |t_{DLHm} - t_{DLHn}|, t_{OSHL} = |t_{DHLm} - t_{DHLn}|$

Note2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

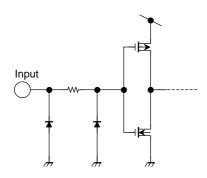
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$



Noise Characteristics (Input: $t_r = t_f = 3 \text{ ns}$)

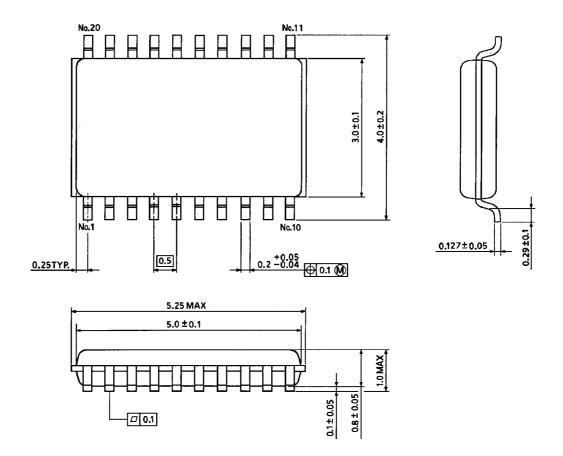
Characteristics	Symbol	Test Condition		Ta = 25°C		Unit
Gilalacteristics	Syllibol	rest Condition	V _{CC} (V)	Тур.	Limit	Uill
Quiet output maximum dynamic V _{OL}	V _{OLP}	C _L = 50 pF	5.0	0.5	0.8	V
Quiet output minimum dymnamic V _{OL}	V _{OLV}	C _L = 50 pF	5.0	-0.5	-0.8	V
Minimum high level dynamic input voltage V_{IH}	V_{IHD}	C _L = 50 pF	5.0	_	3.5	V
Maximum low level dynamic input voltage $V_{\rm IL}$	V _{ILD}	C _L = 50 pF	5.0		1.5	V

Input Equivalent Circuit



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Package Dimensions



Weight: 0.03 g (typ.)

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